



# BCL016B-343

### **SUPER LOW NOISE PHEMT IN SOT-343 PACKAGE**

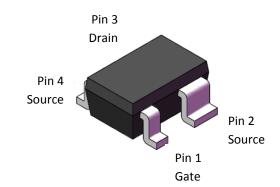
The BeRex BCL016B-343 is a GaAs super low noise pHEMT in a standard SOT-343 plastic package. It has a nominal 0.15 micron gate length and 160 micron gate width making the product ideally suited for applications requiring very low noise and high associated gain. The BCL016B-343 offers high insertion gain and a low noise figure for L to C band amplifiers applications.

### **PRODUCT FEATURES**

- Low 0.2 dB typical noise figure @2.4 GHz
- High 18 dB Typical associated Gain @2.4 GHz
- Typical OIP3 21 dBm at 2.4 GHz
- Industry standard SOT-343 package

### **APPLICATIONS**

- Satellite Radios
- L to C band low noise amplifiers
- Test & Measurement



# **ELECTRICAL CHARACTERISTICS (T<sub>a</sub> = 25° C)**

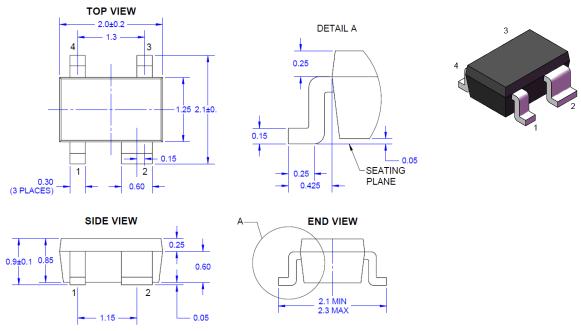
SYMBOL	PARAMETER/TEST CONDITIONS	FREQ.	MIN.	TYPICAL	MAX.	UNIT
NF	Noise Figure (Vds = 2V, Id = 10mA)	2.4 GHz 5.8 GHz		0.2 0.4		dB
$G_A$	Associated Gain (Vds = 2V, Id = 10mA)	2.4 GHz 5.8 GHz		18 13		dB
P1dB	Output Power @ p1dB (Vds = 2V, Id = 10mA)	2.4 GHz 5.8 GHz		10 10		dBm
OIP3	0 dBm output power/tone, 1 MHz spacing	2.4 GHz 5.8 GHz		21 21		dBm
I <sub>DSS</sub>	Saturated Drain Current (Vgs = 0V, Vds = 2V)			50		mA
$G_M$	Transconductance (Vds = 2V, Vgs = -0.3V)			120		mS
$V_P$	Pinch-off Voltage (Vds = 2V, Id = 200μA)			-0.7		V
$BV_GD$	Gate-Drain Breakdown Voltage, (Ig = -200 μA, source open)			9		V
$BV_GS$	Gate-Source Breakdown Voltage, (Ig = -200 μA, drain open)			6		V

# MAXIMUM RATING $(T_a = 25^{\circ} C)$

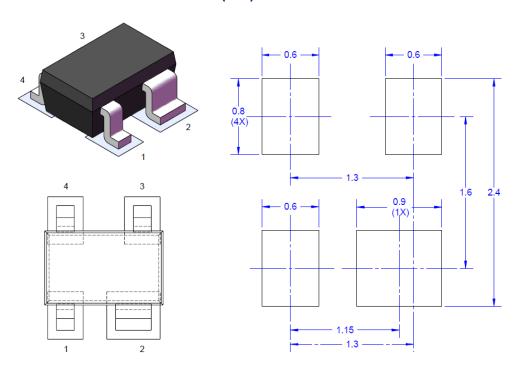
SYMBOLS	PARAMETERS	ABSOLUTE MAX.
V <sub>DS</sub>	Drain-Source Voltage	5 V
$V_{GS}$	Gate-Source Voltage	-3 V
I <sub>DS</sub>	Drain Current	50 mA
I <sub>GSF</sub>	Forward Gate Current	30 mA
P <sub>IN</sub>	Input Power	20 dBm
T <sub>CH</sub>	Channel Temperature	150° C
T <sub>STG</sub>	Storage Temperature	-60° C - 150° C
$P_{T}$	Total Power Dissipation	200 mW

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# **PACKAGE DEMENSIONS in Millimeters (mm)**



# PC BOARD LAND PATTERN in Millimeters (mm)





Proper ESD procedures should be followed when handling this device.

### **HANDLING PRECAUTIONS:**

GaAs FETs are very sensitive to and may be damaged by Electrostatic Discharge (ESD). Therefore, proper ESD precautions must be taken whenever you are handling these devices. It is critically important that all work surfaces, and assembly equipment, as well as the operator be properly grounded when handling these devices to prevent ESD damage.

### **CAUTION:**

THIS PRODUCT CONTAINS GALLIUM ARSENIDE (GaAs) WHICH CAN BE HAZARDOUS TO THE HUMAN BODY AND THE ENVIRONMENT. THEREFORE, IT MUST BE HANDLED WITH CARE AND IN ACCORDANCE WITH ALL GOVERNMENTAL AND COMPANY REGULATIONS FOR THE SAFE HANDLING AND DISPOSAL OF HAZARDOUS WASTE. DO NOT DO NOT BURN, DESTROY, CUT, CRUSH OR CHEMICALLY DISSOLVE THE PRODUCT. DO NOT LICK THE PRODUCT OR IN ANY WAY ALLOW IT TO ENTER THE MOUTH. EXCLUDE THE PRODUCT FROM GENERAL INDUSTRIAL WASTE OR GARBAGE AND DISPOSE OF ONLY IN ACCORDANCE TO APPLICABLE LAWS AND/OR ORDINANCES.

#### **DISCLAIMER**

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- A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.